

Title (en)
Display device with improved grid structure

Title (de)
Flache Anzeigevorrichtung mit verbesserter Elektrodenstruktur

Title (fr)
Dispositif d'affichage à panneau plat et structure d'électrodes améliorée

Publication
EP 0987732 A3 20020911 (EN)

Application
EP 99306604 A 19990820

Priority
US 13822698 A 19980821

Abstract (en)
[origin: EP0987732A2] A rim made of glass or ceramic material is attached to an alloy sheet with through holes therein at an elevated temperature. Voltages applied to the sheet may be used for focusing electrons passing there through onto a phosphor layer for displaying images. An optional insulating layer is formed on the sheet and optional grid electrodes are formed on the insulating layer for addressing and focusing. Upon cooling, the rim maintains the alloy sheet in tension. Holes in the alloy sheet and the grid electrodes are therefore maintained in proper alignment with cathodes and pixel dots despite temperature variations. The rim also forms a portion of the side wall of the display device, so that once the rim has been aligned with and attached to a cathode plate and face plate, the accurate alignment process has been completed and the assembly of the device is much simplified. By employing a thin rim and substrate, the combined electrode structure may be as thin as 3 millimeters or less, so that the distance between the face and back plates is no more than 10 millimeters, suitable for an ultrathin large screen display. <IMAGE>

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H01J 9/18; **H01J 31/12**; **H01J 29/02**

IPC 8 full level
H01J 9/14 (2006.01); **H01J 9/18** (2006.01); **H01J 29/02** (2006.01); **H01J 29/07** (2006.01); **H01J 29/62** (2006.01); **H01J 31/12** (2006.01)

CPC (source: EP US)
H01J 9/185 (2013.01 - EP US); **H01J 29/028** (2013.01 - EP US); **H01J 31/123** (2013.01 - EP US); **H01J 2329/863** (2013.01 - EP US)

Citation (search report)
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